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All-inorganic copper-halide perovskites for large-Stokes shift and ten-nanosecond-emission scintillators†

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The recent surge of interest in low-dimensional lead-free copper halide perovskites (CHPs) has driven significant progress in optoelectronics and scintillating materials. However, the development of greenbased synthetic routes for CHPs, aimed at creating fast-decaying scintillators with ultrasensitive X-ray detection, remains elusive. In this study, we utilize a mechanochemical method to obtain 1D CHP $(CsCu_2I_3)$ and 0D CHPs $(Cs_3Cu_2X_5 (X = I, Br))$ focusing on the mixing of I and Br anions with different molar ratios (I: Br = 4:1 and 3:2). CsCu₂I₃ and Cs₃Cu₂I₅ exhibit a substantial large Stokes shift (SS) of 1.75 ± 0.02 eV and 1.57 ± 0.05 eV with the former displaying the absence of afterglow, whereas the latter has a deep trap of \sim 500 meV, complicating the scintillation mechanism and resulting in a slower decay component. The CsCu₂I₃ scintillation decay time is primarily characterized by a fast component (τ_1) of 9.30 \pm 0.01 ns, accounting for contribution (C₁) of 43% from the total emission. This fast decay component of ~10 ns has not been previously reported in the family of CHPs. Similarly, τ_1 of 10.9 \pm 0.6 ns is obtained in $Cs_3Cu_2l_5$, but when compared to its counterpart, C_1 is only 3%. Upon increasing the Br substitution in Cs₃Cu₂I₅, we observe that the traps become shallower, with energies ranging from 208 \pm 21 to 121 \pm 18 meV, along with an appreciable trap concentration of ~10⁴. The C₁ of τ_1 also increases with higher Br concentration, reaching a maximum value of 29%. Unfortunately, this increased contribution in decay times is accompanied by a decrease in light yields (Cs₃Cu₂I₅ has 16.5 ph per keV at room temperature (RT)) as thermal quenching processes predominate throughout the entire series of CHPs at RT. Our work provides valuable insights into the tunable structure-property relationship through the I:Br composition ratio of CHPs, hence advancing scintillation performance by rational design towards timing applications.

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1 Introduction

Lead halide perovskites have been attractive for scintillation detection due to their high quantum yield and their potential for X-ray imaging applications.^{1–3} A light yield (LY) of 24 ± 2 ph per keV and a decay time of 5.97 ns have been achieved for CsPbBr₃ nanocrystals.⁴ Moreover, CsPbBr₃ nanocrystals embedded into zero-dimensional (0D) Cs₄PbBr₆ microstructure materials have shown a high LY of 64 ± 2 ph per keV and a fast scintillation time of 1.3 ns (88%) and 6.7 ns (12%).⁵ Unfortunately, the commonly used heavy metal lead in perovskites is still a major concern due to its toxicity.⁶ Furthermore, the relatively poor stability⁷ and strong light self-absorption⁸ are also the major challenges for the introduction of lead-based materials into the marketplace. To address these issues,

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research efforts have been devoted to developing lead-free halide perovskites.^{9,10} In this regard, copper halide perovskites (CHPs) have been considered as alternatives due to their stability and bright emission,^{11–15} especially in the stable form of Cu¹⁺.¹⁶ Substituting Pb with Cu has been previously reported to lead to a larger Stokes shift (SS), which may be beneficial to enhance LY by suppressing the reabsorption loss.^{10,17} Cheng et al. have reported the LYs of one-dimensional (1D) CsCu₂I₃ and zero-dimensional (0D) Cs₃Cu₂I₅ single crystals to be 16 ph per keV and 32 ph per keV, respectively.^{17,18} Some larger LYs were also observed for Tl-doped and nanocrystal-formed Cs₃Cu₂I₅.^{13,19} However, the slow scintillation decay remains a major concern, given that the previously reported fast component of scintillation decay is 39 ns (82%) for Cs₃Cu₂I₅ singlecrystals.²⁰ This value is still far from competing with lead-based perovskites, and thus faster scintillation decay is still necessary to be pursued for practical timing application.³ To note, several strategies have been adopted to regulate the scintillation and luminescence properties such as phase control, doping, the pressure effect, polarization dependence, and chemical composition.²¹⁻²⁶ The last approach is quite feasible and attractive since it allows access to bandgap control and emission tuning via halogen substitution.^{27,28} For a comparison, Roccanova et al. reported a powdered form of CsCu₂Br_{1.5}I_{1.5} with the PL peak and SS at 584 nm and 249 nm, respectively.¹² In addition, the powdered forms of Cs₃Cu₂Br_{1.25}I_{3.75}, Cs₃Cu₂. Br_{2.5}I_{2.5} and Cs₃Cu₂Br_{3.75}I_{1.25} have been reported with tunable PL peaks (456-443 nm) and SSs (164-135 nm); however, the corresponding LYs are not investigated.²⁹ Thus, the scintillation properties at the different I:Br ratios remain elusive in these intriguing mixed-halide CHP systems.

The widely adopted solution processing methods for perovskites use organic solvents such as N,N-dimethylformamide and dimethyl sulfoxide solutions which are not green.^{30,31} On the other hand, mechanochemistry offers a simpler and faster synthesis method without the employment of complex organic solvents and heat treatment.32,33 Through this method, all inorganic CHPs have been successfully synthesized with bright emission.^{32,34} Here, we investigate the potential of the mechanochemical synthesis method for CHPs and study their scintillation properties. First, we vary the molar ratio of CsI and CuI precursors and characterise their scintillation properties. Both Cs₃Cu₂I₅ and CsCu₂I₃ have similar LY (13 and 16.5 ph per keV, respectively) and 10 ns scintillation decay fast component. This is faster than those reported before for $Cs_3Cu_2I_5$ and $CsCu_2I_3.^{13,17\text{--}19}$ In different dimensionalities, $Cs_3Cu_2I_5$ has a smaller SS and higher LY, but slower average decay time than those of CsCu₂I₃. The average slow decay times are attributed to the presence of dominating slow components between 100 and 1000 ns. In this study, we add the CsBr precursor for Br doping in Cs₃Cu₂I₅ to increase the contribution of 10 ns fast components to the emission. However, the LYs of Cs₃Cu₂I₃Br₂ decrease maximally down to one of the third from that of Cs₃Cu₂I₅. Therefore, from this study, we expect that the optimum values of LYs and the contribution of the 10 ns decay component of CHP scintillators can be estimated. Such control of 10 ns scintillation decay components paves the way for scalable, low-cost, and high-throughput production of highquality fast lead-free perovskite scintillators for applications of photon counting computed tomography (PCCT) and positron emission tomography (PET).³

2 Experimental

2.1 Synthesis

Caesium iodide (CsI, anhydrous, 99.9999% trace metal basis), copper iodide (CuI, anhydrous, 99.9999% trace metal basis), and caesium bromide (CsBr, anhydrous, 99.9999% trace metal basis) were obtained from Sigma-Aldrich. Acetone (ACS Reag., for analysis) was acquired from Millipore. All chemicals were used as received without undergoing any purification steps. All samples of CHPs were synthesized mechanochemically, CsI and CuI, in 1:2 and 3:2 molar ratios as carried out in a previous report,³³ and were each ground for 10 minutes with 300 µL of acetone, hereinafter referred to as CsCu₂I₃ and Cs₃Cu₂I₅, respectively. The same method was used for CsI, CuI, and CsBr in the molar ratios of 2:2:1 and 1:2:2, hereinafter referred to as Cs₃Cu₂I₄ Br and Cs₃Cu₂I₃Br₂, respectively. The grinding process immediately produced strongly blueemitting and yellow-emitting powders, as shown in Fig. S1a-d (ESI[†]), indicating the formation of the desired perovskites.³³

2.2 Scanning electron and transmission electron microscopy

Sample micrographs were taken at 5 kV accelerating voltage in the secondary electron mode using a ZEISS EVO MA10 scanning electron microscope (SEM) system with 1.00 K times magnification. Transmission electron microscopy (TEM) and highresolution TEM (HRTEM) analyses were performed utilizing a double-Cs-corrected Titan G2 60-300 (S)TEM microscope. Before HRTEM analysis, the electron beam conditions were adjusted based on the sample material. In this study, an acceleration voltage of 300 kV was employed. Samples were prepared by dissolving 4 mg of the compound in 4 mL of ethanol, followed by 1 hour sonication. The samples were transferred to Cu holey carbon grids ($\sim 5 \mu L$ droplet) and allowed to dry. Both TEM and STEM modes were employed, also at very high magnifications allowing high-resolution imaging. For image acquisition, the Ultrascan US1000 camera was used for TEM and the HAADF detector for STEM. The STEM-EDS maps were also acquired with a Super-X EDS detector. Due to sample sensitivity to the beam, the data were collected with the smallest possible dose at the expense of the signal-to-noise ratio, which is particularly seen on EDS maps.

2.3 Fourier-transform infrared and Raman spectroscopies

Fourier-transform infrared (FTIR) spectra were obtained using an ATR-FTIR Thermo Scientific Nicolet iS10 spectrometer (ThermoFisher Scientific, USA), covering the spectral range of 800–400 cm⁻¹. The as-synthesised CHPs were directly mounted and compacted into the sample holder without any further preparation. Raman spectra were acquired with a ThermoFisher Scientific DXR instrument (ThermoFisher Scientific, USA) utilizing a 532 nm excitation laser source. The measurements were conducted at room temperature (RT), employing laser powers ranging from 0.2 to 3.0 mW.

2.4 X-ray diffractometry

The structure of the CHPs was inspected with a powder X-ray diffractometer (XRD) (PANalytical AERIS, Malvern Panalytical, the Netherlands) with K α of 1.54 Å. Data acquisition was conducted at RT with a scanning speed of 0.12 s per step and a step size of 0.0217°. Further Rietveld refinement was carried out using Profex,³⁵ while visualization system for electronic and structural analysis (VESTA) was used for crystallography visualisations.³⁶

2.5 X-ray photoelectron spectroscopy

X-ray photoelectron spectroscopy (XPS) analyzed 1 mm diameter samples using a magnesium K α X-ray source (excitation energy at 1254 eV). For calibration, the Ag $3d_{5/2}$ peak (centered at 368.10 eV) from argon-ion-sputtered silver foil was utilised. CasaXPS software package was used for deconvolution analysis.³⁷

2.6 Density functional theory calculations

Density functional theory (DFT) calculations were performed under the Kohn-Sham formulation^{38,39} as implemented in the Vienna ab initio simulation package (VASP).^{40,41} The projector augmented wave (PAW) method^{42,43} was used to describe the interaction between ion cores and electrons. The electron exchange-correlation was treated using spin polarization by the generalized gradient approximation (GGA) method based on the Perdew-Burke-Ernzerhof (PBE) functional.44 The rotationally invariant GGA+U approach introduced by Dudarev et al.⁴⁵ was used with an effective Hubbard parameter $U_{\rm eff}$ being 11.0 eV for the Cu d orbital. The plane wave basis sets with a cut-off energy of 500 eV were used for all calculations. The Brillouin zone was sampled according to the Monkhorst-Pack scheme⁴⁶ with a k-point grid of $3 \times 3 \times 5$. The zerodamping D3 method⁴⁷ was adopted to account for the dispersion correction. During calculations, all atoms were allowed to fully relax. The conjugate gradient method was employed for cell optimizations, and the calculations were considered to converge when the maximum forces on each atom were less than $0.01 \text{ eV} \text{\AA}^{-1}$.

2.7 Absorption and photoluminescence

The samples were excited for photoluminescence (PL) measurement using a picosecond laser diode (Master Oscillator Fibre Amplifier, Picoquant GmbH, Berlin, Germany) with a repetition rate of 31.25 kHz and a wavelength of 266 nm. The laser diode had a pulse duration of 50 ps and an average power of 2 mW at RT. Excitation focusing and signal collection were carried out using a microscope objective (Nikon Corporation, Tokyo, Japan) with a magnification of $20 \times$ and a numerical aperture of 0.4. The PL signal was filtered and acquired using a highsensitivity visible light spectrometer (Ocean Optics, Florida, USA). Absorption spectra were measured with a homemade setup with the same commercial spectrometer in the transmission mode. Since the samples were put inside the quartz tubes, the spectra were corrected for the absorption of the tubes.

2.8 Temperature-dependent radioluminescence

For radioluminescence (RL) measurement, X-ray excitation was performed using an Inel XRG3500 X-ray generator with a Cuanode tube operating at 45 kV/10 mA. The RL signal was recorded using an Acton Research Corporation SpectraPro-500i monochromator equipped with a 500 nm blazed grating and a Hamamatsu R928 photomultiplier. The temperature of the sample was controlled using an APD Cryogenics Inc. closedcycle helium cooler, along with a Lake Shore 330 programmable temperature controller, in the range of 10 to 350 K. To prevent any thermal release of charge carriers, measurements were carried out in reverse, starting at 350 K and ending at 10 K.

2.9 Thermoluminescence

Thermoluminescence (TL) measurement involved exposing the samples to X-ray excitation for 600 s at 10 K, followed by observing the afterglow upon X-ray cessation. After a waiting period of at least 2500 s to ensure decay of the afterglow, TL glow peaks were recorded while raising the temperature from 10 K to 350 K at a rate of 0.14 K s⁻¹.

2.10 Pulse height and scintillation decay

We used a 137 Cs (662 keV) radioisotope for the γ -ray source and a Hamamatsu R878 photomultiplier (PMT) for detecting the converted photons. To operate the PMT, we applied a voltage of 1.25 kV. The corresponding output signal from the PMT is integrated with a charge-sensitive pre-amplifier. The output then feeds a spectroscopic amplifier with a shaping time of 2 µs and an analog-to-digital converter (Ortec series). The photoelectron yield was obtained by comparing the position of the photopeak to the position of the mean value of the single electron response in pulse high spectra measurements. The actual LY for the radiation conversion in photons per MeV was obtained after the photoelectron yield was divided by the quantum efficiencies of the PMT. Scintillation decay measurements were performed by the delayed coincidence single photon counting method.⁴⁸ A ¹³⁷Cs radioactive source, two Hamamatsu photomultiplier tubes (R1104 and R928 for "starts" and "stops", respectively), a Canberra 2145 time-toamplitude converter, and a TUKAN-8K-USB multichannel analyzer were used.

3 Results and discussion

In Fig. 1a, the attenuation length of the CHPs is compared with the attenuation length of $CsPbX_3$ (where X = Br or I).⁴ In the range of 10 to 33 keV, the attenuation length of $CsPbX_3$ is shorter than that of the CHPs. In the range of 33 to 42 keV however, the attenuation length of the CHPs outperforms that of CsPbBr₃, and is still shorter than that of CsPbI₃ of up to 46 keV. In the case of the CHPs, the doping of bromine results



Fig. 1 (a) X-ray attenuation lengths for the investigated caesium copper halide perovskites (CHPs) with CsPbI₃ and CsPbBr₃ used as in ref. 4. (b) XRD spectra of the CHPs. Band structures and density of states of (c) $CsCu_2I_3$, (d) $Cs_3Cu_2I_5$, (e) $Cs_3Cu_2I_4$ Br, and (f) $Cs_3Cu_2I_3$ Br₂.

in a longer, less effective attenuation length compared to the undoped CHPs within this energy range. The CHPs hold promise for medical or security imaging applications within the X- or γ -ray energy spectrum.

Subsequent to grinding, the morphology of CHPs was inspected with SEM, as displayed in Fig. S2a-d (ESI[†]). The CsCu₂I₃ powder has a rod-like shape, while Cs₃Cu₂I₅, Cs₃Cu₂I₄ Br, and $Cs_3Cu_2I_3Br_2$ have particle-like shape, suggesting that a different crystal system is present between the two configurations. The particle size distribution observed from SEM is displayed in Fig. S3a-d (ESI⁺). To investigate the CHPs in smaller dimensions, TEM, HRTEM, and EDS mapping are displayed in Fig. S4 (ESI†). Major peaks of XRD patterns depicted in Fig. 1b indicate that a structural difference is present between CsCu2I3 and Cs3Cu2X5 compounds. A shift to a higher angle is observed with increasing Br doping concentration in Cs₃Cu₂I₅, Cs₃Cu₂I₄ Br, and Cs₃Cu₂I₃Br₂, which can be attributed to the decrease of lattice distance. Rietveld refinement was further carried out with calculated CIF, as displayed in Fig. S5 (ESI⁺), confirming the orthorhombic structure shared by all of the CHPs. The 1D CsCu₂I₃ XRD pattern was best fitted with the Cmcm space group, while the 0D Cs₃Cu₂I₅, Cs₃Cu₂I₄ Br, and Cs₃Cu₂I₃Br₂ were best fitted with the *Pnma* space group. Furthermore, the refinement parameters shown in Table S1 (ESI[†]) reveal that the increased concentration of Br doping reduces the unit cell volume, from 1698.750 \pm 0.046, to 1679.527 ± 0.047 , and to $1637.956 \pm 0.617 \text{ Å}^3$ for $Cs_3Cu_2I_5$, Cs₃Cu₂I₄ Br, and Cs₃Cu₂I₃Br₂, respectively. This trend is consistent with CHPs synthesised by solution-processing and mechanochemistry.^{33,49,50} In the case of CHPs, its fundamental structure is typically arranged in a tetrahedral form. This is quite distinct from the octahedral configuration commonly found in Pb-based,⁴ PbBi halide double perovskite,⁵¹ and various lead-free halide perovskites such as 2D Cu-,⁵² Sn-^{53,54} Mn-based,⁵⁵ and AgBi halide double perovskites.⁵⁶ This structural divergence leads to two different views in the community, with some not recognising CHP as a perovskite. Nevertheless, a part of the community perceives CHP as a variant of perovskites,^{57–60} a stance which is adopted in this study. FTIR and Raman spectra of the CHPs are presented in Fig. S6 and S7 (ESI[†]), respectively. Additionally, XPS analysis confirms the presence of metal cations (Cs and Cu) and anions (I and Br) accordingly, as shown in Fig. S8 (ESI[†]).

Rational design carried out by modifying the I:Br molar ratio of 0D CHPs not only affects the crystallographic structure of the CHPs, but can also be used to modify band gaps and optoelectronic properties. We proceeded to determine the density of states (DOS) utilising DFT and the optical bandgap. Fig. 1c-f displays the band structure, inclusive of the total (black) and individual (coloured) DOSs for CsCu₂I₃, Cs₃Cu₂I₅, $Cs_3Cu_2I_4$ Br, and $Cs_3Cu_2I_3Br_2$. Within the DOS, Cu d is symbolised by the blue line, Cs d by pink, I p by red, and Br p by green. The calculated band gaps are 3.23 \pm 0.20, 3.38 \pm 0.20, 3.37 \pm 0.20, and 3.36 \pm 0.20 eV for CsCu₂I₃, Cs₃Cu₂I₅, Cs₃Cu₂I₄ Br, and Cs₃Cu₂I₃Br₂, respectively. All CHPs exhibit a direct band gap at the Γ point. Given that Cu states majorly influence both the conduction and valence bands, the band gaps for Cs₃Cu₂I₅, Cs₃Cu₂I₄ Br, and Cs₃Cu₂I₃Br₂ are strikingly similar to each other. The calculated band gaps for CsCu₂I₃ and Cs₃Cu₂I₅ concur with prior findings from the Kubelka-Munk plot¹² and the hybrid HSE06 functional.⁶¹

The optical properties of the CHPs were investigated by collecting their absorption and PL emission spectra, as shown in Fig. 2. The maximum absorbance of the CHPs is 3.83, 4.08, 4.11, and 4.16 eV for CsCu₂I₃, Cs₃Cu₂I₅, Cs₃Cu₂I₄ Br, and Cs₃Cu₂I₃Br₂, respectively. From the absorption spectra, we obtain



Fig. 2 Absorption (dark blue lines) and photoluminescence (red lines) spectra of the CHPs measured at RT.

the band gaps through Elliott fitting (see eqn (S1) and S2 (ESI[†]))⁶² as depicted in Fig. S9 (ESI⁺). As summarised in Table 1, the experimental band gaps ($E_{
m g}^{
m exp}$) are 3.72 \pm 0.02, 3.96 \pm 0.05, 3.99 \pm 0.03, and 4.08 \pm 0.02 eV for CsCu₂I₃, Cs₃Cu₂I₅, Cs₃Cu₂I₄ Br, and Cs₃Cu₂I₃Br₂, respectively. From these data, we further calculated the SS, determined as the difference between E_{g}^{exp} and maximum PL emission.63 All CHPs exhibit large SS with negligible selfabsorption, as the characteristics of the CHPs. For example, the 1D yellow-emitting CsCu₂I₃ has a vast PL spectrum, showcasing a peak PL intensity at 2.07 eV. This leads to an SS of 265.23 \pm 1.78 nm (1.65 \pm 0.02 eV). Lowering the dimensionality causes the PL maximum to blue-shift, with the PL peak for Cs₃Cu₂I₅ standing at 2.57 eV, correlating with an SS of 168.73 \pm 3.91 nm (1.39 \pm 0.05 eV). The addition of a Br dopant to Cs₃Cu₂I₅ induces a red shift in the PL peaks, registering values of 2.55 eV for Cs₃Cu₂I₄ Br and 2.54 eV for Cs₃Cu₂I₃Br₂. The incorporation of Br also results in a SS of 176.39 \pm 2.35 nm (1.45 \pm 0.03 eV) for Cs_3Cu_2I_4 Br and $183.25 \pm 1.48 \text{ nm} (1.53 \pm 0.02 \text{ eV})$ for Cs₃Cu₂I₃Br₂, respectively. An increased concentration of Br doping is known to produce a larger SS, paired with a red shift in the PL peak emission trend.²⁹ For CsCu₂I₃, the SS is higher and comparable to its single-crystal (257 nm),⁶⁴ nanocrystals (240 nm),⁶⁵ and mechanochemically synthesised powder (244 nm)³³ form. For Cs₃Cu₂I₅, the SS is also comparable to and larger than those of its single-crystal (141 nm),⁴⁹ nanocrystals (161 nm),¹³ thin film (156 nm)⁶⁶ and mechanochemically synthesised powder (130 nm)³³ form. The SS of the CHPs herein is much larger than those of Pb-based ones, as

summarised in Table S3 (ESI[†]), along with their other comparable optical properties. All the CHPs exhibited a relatively broad PL emission spectrum compared to other forms, with full-width-athalf-maxima (FWHM) ranging from 0.37 to 0.67 eV. As a case in point, the FWHM of $CsCu_2I_3$ for single-crystals is 75 nm⁹ as reported by Lin *et al.*, while that for a mechanochemically synthesised powder is 120 nm³³ as reported by Grandhi *et al.* We attribute the relatively broad PL emission spectra and their variation to the irregularities that may be caused by the hand-grinding approach. We further comment on the reproducibility of the experimental approach with PL reliability study as depicted in Fig. S10 (ESI[†]).

RL study was conducted to examine emission characteristics of the CHPs in the cryogenic state and at RT. RL spectra of the CHPs measured in the temperature range of 10 to 350 K are presented in Fig. 3a-d. The alteration of dimensionality shows a significant change in their RL properties. Upon excitation by an X-ray source, the 1D CsCu₂I₃ exhibits an increase in the RL intensity from the temperature of 10 up to \sim 230 K, showing that CsCu₂I₃ is suitable for RL within this range. The RL intensity above 270 K is weakened before reaching RT, indicating thermal quenching (TQ) behaviour. It is also notable that the RL peak is blue-shifted as the temperature increases, from \sim 579 nm at \sim 60 K to \sim 562 nm at \sim 173 K. We discuss that the physical origin of such peak-shifting behaviour is mainly related to the temperature effect on the luminescent centre of the 1D CHP system. In contrast to CsCu₂I₃, the 0D Cs₃Cu₂I₅ exhibits an RL peak at \sim 445 nm, commencing at a very low temperature and demonstrating a slight red shift in RL maxima as the temperature rises. Upon approaching RT, the RL intensity diminishes, showing TQ. This finding aligns similarly to solution-grown Cs₃Cu₂I₅ single crystals.^{67,68} The increased doping of Br, however, results in TQ occurring earlier. Br doping onto the conventional 0D CHP has a non-negligible impact on contour mapping, which broadens the RL intense peak wavelength. TQ behaviour can also be seen with the broadening of RL FWHM as the temperature increase. For example, the FWHM of CsCu₂I₃ at 150 K is 81.93 nm, while at 200 K it broadens to 90.46 nm. In Cs₃Cu₂I₅, Cs₃Cu₂I₄ Br, and Cs₃Cu₂I₃Br₂, the FWHM also broadens from 54.56, 61.40, and 73.09 nm at 150 K to 61.85, 69.42, and 79.43 nm at 200 K. The RL emission peak aligns closely with the PL peaks, suggesting a shared radiative recombination path.¹³ The variety of emissive transitions of CHPs in different dimensionality shows the possibility of RL property tuning by rational design.

In the scintillation mechanism, the depth and concentration of traps are key determinants of the scintillation characteristics

Table 1 Summary of the optical properties of the CHPs, where E_g^{exp} is the bandgap values obtained with Elliott fitting, σ^2 as depicted in Fig. S9 (I							Fig. S9 (ESI)	
СНР	$E_{\rm g}^{ m calc}$ (eV)	$E_{\rm g}^{\rm exp}$ (eV)	Abs. maximum (eV)	PL maximum (eV)	Stokes shift (SS) (nm)	Stokes shift (SS) (eV)	FWHM (nm)	FWHM (eV)
CsCu ₂ I ₃	3.23 ± 0.20	3.72 ± 0.02	3.83	1.97 ± 0.01	294.49 ± 2.81	1.75 ± 0.02	127.31 ± 6.05	0.20 ± 0.01
Cs ₃ Cu ₂ I ₅	3.38 ± 0.20	3.96 ± 0.05	4.08	2.39 ± 0.01	203.54 ± 4.35	1.57 ± 0.05	102.26 ± 3.01	0.19 ± 0.01
Cs ₃ Cu ₂ I ₄	Br 3.37 ± 0.20	3.99 ± 0.03	4.11	2.54 ± 0.01	119.31 ± 21.92	0.83 ± 0.20	87.18 ± 2.66	0.18 ± 0.01
Cs ₃ Cu ₂ I ₃	$Br_2 3.36 \pm 0.20$	4.08 ± 0.02	4.16	2.55 ± 0.01	176.08 ± 3.00	$\textbf{1.44} \pm \textbf{0.03}$	83.26 ± 3.00	0.17 ± 0.01





Fig. 3 Radioluminescence spectra across different wavelengths at different temperatures ranging from 10 to 350 K of (a) $CsCu_2I_3$, (b) $Cs_3Cu_2I_5$, (c) $Cs_3Cu_2I_4$ Br, and (d) $Cs_3Cu_2I_3Br_2$.

of the CHPs. Herein, the trap state properties of the CHPs are investigated *via* TL characterisation, as presented in Fig. 4. Steady-state TL measurements at 10 K depict the absence of decay after the X-ray source is turned off. The absence of afterglow in all CHPs shows the absence of super shallow traps. Typically, this afterglow phenomenon is commonly observed in all-inorganic lead halide and hybrid organic–inorganic tinbased perovskites, as reported in our prior research.^{10,69} During the TL experiments, we waited for 2500 seconds after we switched off the X-ray source and subsequently raised the



Fig. 4 Afterglow and thermoluminescence of CHPs. The red dashed lines indicate the temperature changes over time.

temperature of the respective CHPs sample from 10 to 350 K. The purpose of such sequence is to eliminate the afterglow contribution to the background intensities. This temperature increase revealed observable TL peak intensities for all CHPs except the 1D CsCu₂I₃. For CsCu₂I₃, the lack of an emission signal with increasing temperature indicates that both shallow and deep traps are absent. To reveal the depth and concentration of traps, a glow curve fitting with the Randall-Wilkins equation as depicted in Fig. S11 (ESI[†]) was carried out towards the 0D CHPs.^{1,70} The fitting parameters summarised in Table S4 (ESI[†]) reveal that the depth of traps for 0D CHPs (all of which are observable below RT) is suppressed with an increase in trap concentration as Br doping is introduced. Trap states in Cs₃Cu₂I₅ are revealed at depths of 271, 512, and 521 meV, while Cs₃Cu₂I₄ Br exhibits trap depths at 151 and 208 meV, and Cs₃Cu₂I₃Br₂ at 121 and 184 meV. These traps can be attributed to the implication of internal scattering and structural defects, with the increment of Br doping.^{71,72} When compared to other metals or organic components in our previous works, the overall relatively low concentration of traps in the order between 10³ and 10⁴ may be partially attributed to the incorporation of Cs⁺ cations.⁷³ These low trap concentration characteristics are also observed in Cs₃Cu₂I₅ single crystals.²⁰

A considerable property in scintillators is a fast scintillation decay time, which is beneficial for timing applications, *e.g.* PET and PCCT. Upon γ -irradiation exposure, the decay times of CHPs were measured at RT in which three-component decay fittings are performed as shown in Fig. 5 (with fitting parameters shown in Table 2). We note that the first component (τ_1) is associated with the direct recombination of excitons, the second component (τ_2) is attributed to the self-trapped excitation (STE), and the third component (τ_3) corresponds to the



Fig. 5 Scintillation decay curves of (a) CsCu₂I₃, (b) Cs₃Cu₂I₅, (c) Cs₃Cu₂I₄ Br, and (d) Cs₃Cu₂I₃Br₂. The red lines indicate the respective three-exponential decay fitting.

recombination of trapped electrons and holes as Frenkel defects.⁷⁴ We found that CHPs exhibit a fast value of τ_1 with varied photon decay contribution. 1D CsCu₂I₃ demonstrated a value of 9.30 \pm 0.01 ns (τ_1 contribution; 43%). Upon lowering the dimensionality, 0D $Cs_3Cu_2I_5$ demonstrated a τ_1 value of 10.90 ± 0.55 ns (τ_1 contribution; 3%). Herein, the overall value of τ_1 of the CHP powder which was synthesized by mechanochemistry is relatively faster than that of the single-crystal of CsCu₂I₃ and Cs₃Cu₂I₅,^{17,18} surpassing a notable fast component of 39 ns (82%) observed on a Cs₃Cu₂I₅ single-crystal synthesised using the aqueous solution method.²⁰ This fast component of \sim 10 ns has also not been previously reported in the family of CHPs and is faster than that of the existing commercial inorganic scintillators, Ce-doped LaBr₃.⁷⁵ Perovskite scintillators in powder form exhibit faster X-ray or scintillation decay times compared to their single crystal or thin film counterparts primarily due to their increased surface area and defect levels.^{76,77} The powder form allows for more efficient energy transfer and quicker electron-hole recombination.78,79 Furthermore, we observed incremental changes in the decay time for the 0D system, where the contribution of τ_3 varied from 387.15 \pm 6.05 ns (27%) for $CsCu_2I_3$ to 924.85 \pm 4.05 (90%) for $Cs_3Cu_2I_5$. It turns out that by doping Br into the Cs3Cu2I5 lattice (Cs3Cu2I4 Br and $Cs_3Cu_2I_3Br_2$, τ_1 of ~ 10 ns is still retained while simultaneously increasing the contribution of τ_1 (10.40 \pm 0.10 ns (12%) for $Cs_3Cu_2I_4$ Br and 11.55 \pm 0.55 ns (29%) for $Cs_3Cu_2I_3Br_2$). It is also worth noting that the contribution of τ_2 is significant in 1D CsCu₂I₃ (54.5 \pm 0.01 ns at 30%) and less dominant in Cs₃Cu₂I₅ (116.15 \pm 0.35 ns at 7%), and it becomes more dominant towards the increased Br doping (116.15 \pm 0.35 ns at 7%, 92.85 \pm 6.95 ns at 11%, and 110.05 \pm 32.85 ns at 15% for Cs₃Cu₂I₅, Cs₃Cu₂I₄ Br, and Cs₃Cu₂I₃Br₂ respectively).

We found that the quantum yield (QY) is enhanced by lowering the CHP dimensionality from 1D CsCu₂I₃ (13.59 \pm 2.85%) to 0D Cs_3Cu_2I_5 (47.19 \pm 8.83%), as summarised in Table 3 (CsPbBr₃ quantum dots were used as a reference, see Fig. S12 and eqn (S4) (ESI⁺)). In particular, we note that the QY of mechanically ground CsCu₂I₃ is fairly comparable to those of its single-crystal (18%)⁸⁰ and nanocrystals (11%)⁶¹ and differs in contrast with those of mechanochemically-synthesised powder $(6\%)^{33}$ and thin films (20.6%).⁸¹ In the case of Cs₃Cu₂I₅, the corresponding QY is fairly competitive compared to those reported for single-crystals (93.5%),⁸⁰ microcrystals (60%),⁴⁸ thin films (up to 91%),^{60,82,83} nanocrystals (87%),⁶¹ and mechanochemically-synthesised powder (62%).33 In terms of the QY value in mechanochemically-synthesised CHPs, we consider this to be related to the irregularities of the handgrinding method. As we introduced the Br dopant onto the perovskite lattices, a lower QY (23.74 \pm 4.15 and 7.37 \pm 1.24% for Cs₃Cu₂I₄ Br and Cs₃Cu₂I₃Br₂, respectively) resulted.

Furthermore, the calculated and experimental LYs at RT (LY^{calc} and LY^{exp}, respectively) are also presented in Table 3. Utilising the QYs, the highest LY^{calc} value in ph per keV is ascertained using eqn (S5) (ESI[†]). LY^{exp} values of the CHPs were determined by the pulse height spectrum method using a ¹³⁷Cs source at 661.7 keV, as shown in Fig. S13 (ESI[†]). Here, we found that the LY^{exp} is lower than its calculated value and this finding is commonly observed in the other scintillation studies. Moreover, we measured pulse height spectra to obtain the LY^{exp} as a function of temperature (10–350 K) as presented in Fig. 6. The values of LY^{exp} at RT relative to Cs₃Cu₂I₅ (16.5 ph per keV) are 0.76 ± 0.03, 0.67 ± 0.06, and 0.33 ± 0.03 for CsCu₂I₃, Cs₃Cu₂I₄ Br, and Cs₃Cu₂I₃ Br₂, respectively. Considering its powder form, the LY of 1D CsCu₂I₃ and 0D Cs₃Cu₂I₅ is comparable to that of

Table 2 Scintillation decay curve parameters of the CHPs where τ_i is the decay time, C_i is the contribution of the decay time, and τ_{avg} is the average decay time

СНР	τ_1 (ns)	C_1 (%)	τ_2 (ns)	C_2 (%)	τ_3 (ns)	C_3 (%)	$\tau_{\rm avg}~({\rm ns})$
CsCu ₂ I ₃	9.30 ± 0.01	43	54.50 ± 0.01	30	387.15 ± 6.05	27	124.88 ± 1.63
Cs ₃ Cu ₂ I ₅	10.90 ± 0.55	3	116.15 ± 0.35	7	924.85 ± 4.05	90	840.82 ± 3.65
Cs ₃ Cu ₂ I ₄ Br	10.40 ± 0.10	12	92.85 ± 6.95	11	873.60 ± 28.50	77	684.13 ± 22.72
$Cs_3Cu_2I_3Br_2$	11.55 ± 0.55	29	110.05 ± 32.85	15	1050.80 ± 129.00	56	604.45 ± 46.15

Table 3 Quantum yield (QY) at RT, calculated light yield (LY^{calc}), experimental light yield (LY^{exp}) measured at 300 K, and electron-hole transfer efficiency (S) of the CHPs

СНР	QY (%)	$LY^{calc}(S = 1)$ (ph per keV)	$\rm LY^{exp}$ relative to $\rm Cs_3 Cu_2 I_5$ at 300 K (× 16.5 ph per keV)	S ^{exp} (%)
CsCu ₂ I ₃	13.59 ± 2.85	15.88 ± 0.08	0.76 ± 0.03	78.70 ± 16.99
$Cs_3Cu_2I_5$	47.19 ± 8.83	51.82 ± 0.23	1 ± 0.21	31.84 ± 6.50
Cs ₃ Cu ₂ I ₄ Br	23.74 ± 4.15	25.87 ± 0.11	0.67 ± 0.06	42.52 ± 7.94
$Cs_3Cu_2I_3Br_2$	$\textbf{7.37} \pm \textbf{1.24}$	7.85 ± 0.03	0.33 ± 0.03	$\textbf{70.06} \pm \textbf{12.40}$



Fig. 6 Temperature-dependent experimental LY (LY^{exp}) spectra of $Cs_3Cu_2l_5$, $Cs_3Cu_2l_4$ Br, $Cs_3Cu_2l_3Br_2$, and $CsCu_2l_3$, normalised to the LY of $Cs_3Cu_2l_5$ at 300 K derived using integrated RL intensities. The vertical dashed line indicates where the value of LY^{exp} is taken using pulse height spectra at RT, see Fig. S13 (ESI†).

the single-crystal CHPs reported by Cheng *et al.*, at 16 ph per keV¹⁷ and 29 ph per keV¹⁸ for $CsCu_2I_3$ and 0D $Cs_3Cu_2I_5$ singlecrystals, respectively. The peak of $CsCu_2I_3$ was observed to be in the temperature range of 100–200 K, showing its potential for use in this temperature range. The temperature-dependent LY spectra also show that the LY intensity is diminished by TQ upon approaching RT. As a side note, the LYs and scintillation decay times of Pb-based perovskites are depicted in Table S5 (ESI†).

In general, we are looking for an optimised composition of CHPs. First, we investigate the 1D CsCu₂I₃. CsCu₂I₃ possesses large SS, a notable contribution from its rapid scintillation decay component (9.30 \pm 0.01 ns for 43%), and its attenuation length is shorter than that of Pb-based perovskites for energies between 33 and 42 keV (see Fig. 1a). In our pursuit to shorten attenuation length and to enhance LY and QY, we transitioned from the structure of CsCu₂I₃ to Cs₃Cu₂I₅ through rational design by adjusting the molar ratio of its constituents. This transition to Cs₃Cu₂I₅ resulted in a reduced attenuation length, a boost in QY (13.59 \pm 2.85 to 47.19 \pm 8.83%), and an elevated LY (0.76 \pm 0.03 to 1 \pm 0.21 \times 16.5 ph per keV). Yet, a trade-off was observed, which is an extended scintillation decay due to the augmented τ_3 component. We also observe deep traps within the Cs₃Cu₂I₅ system. In an attempt to tune the properties, we introduced Br doping into the 0D Cs₃Cu₂I₅ through rational design. Br doping proves to produce 0D CHPs with shallower and more concentrated traps (see Table S4 (ESI⁺)), an

increase in scintillation decay fast component (see Table 2), but as a consequence of longer attenuation length for energies between 33 and 43 keV, and lower LY (see Table 3). The trend of less efficient QY in contrast with a more efficient S indicates that defects are necessary to induce transport.^{20,68,84} The localisation of excitons achieved by rational design is attributed to the tunable optical and scintillation properties of the CHPs.

Herein, we evaluate the presence of multiple STEs in CHPs from the theoretical^{61,85–88} perspectives and experimental findings⁴⁹ that are mainly governed by the direct consequence of exciton localisation and excited-state structural reorganization.⁸⁹ As the latter, the energetic positions can be modulated by altering the halogen composition of spatially isolated Cu-X polyhedra *via* rational design. According to the absorption and PL results (see Table 2), we schematically propose the configuration coordinate of the mixed halide CHP with I:Br molar ratios of 4:1 and 3:2 in Fig. 7a and b, respectively. It turns out that the energetic difference between STEs to the ground states of the two ratios is almost negligible (~10 meV), which is lower than thermal activation energy (~25 meV). Thus, we believe that the STE emission efficiency (radiative recombination profile) would not differ substantially from the perspective of the energetic landscape approach.



Fig. 7 The configuration coordinate diagrams of the STE process of (a) $Cs_3Cu_2I_4$ Br and (b) $Cs_3Cu_2I_3Br_2$. The theoretical bond length and angle of (c) $Cs_3Cu_2I_4$ Br and (d) $Cs_3Cu_2I_3Br_2$, extracted from theoretical structural files by the VESTA software package.³⁶

On the other hand, previous reports^{21,85,90} have shown that the STE emissions of either 1D or 0D are marginally substantiated due to the lattice deformation mode.⁹¹

In CHPs, the geometric configuration of the crystals plays a critical role in influencing the self-trapped excitation mechanism, which in turn significantly affects the absorption and luminescence processes, as well as the optical and scintillation properties. Hence, we proceed to extend our discussion in these mixed halide CHP systems by interpreting the calculated geometric structure acquired from DFT calculations, as exemplified in Fig. 7c $(Cs_3Cu_2I_4 Br)$ and 7d $(Cs_3Cu_2I_3Br_2)$. The Cu1-X bond lengths of Cs₃Cu₂I₅, Cs₃Cu₂I₄ Br, and Cs₃Cu₂I₄ Br obtained from the structural CIFs notably display a bond length reduction. For example, as we lowered the CHP dimension from 1D CsCu₂I₃ (2.61 Å), the bond length is shortened to 2.56 Å for 0D Cs₃Cu₂I₅ (see Fig. S14 and Table S6 (ESI⁺)). This is in agreement with the previous finding by Ma et al. in thin films.⁹¹ When the I atom is substituted by a single Br atom (Fig. 7c), the Cu1-Br1 bonds are measured at \sim 2.41 Å in the case of Cs₃Cu₂I₄ Br. Upon the substitution of Br atoms, the bond length is found to be 2.40 Å for Cs₃Cu₂I₃Br₂. We also fairly compare CHP structural changes in terms of their bond angles as depicted in Fig. 7c and d. I1-Cu1-I1 angles are determined at ~116.42° (CsCu₂I₃) and 117.07° (Cs₃Cu₂I₅). Upon Br doping, we find that the Br1-Cu1-I1 angle is 116.59° (Cs₃Cu₂I₄ Br) and slightly reduced to 116.00° (Cs₃Cu₂I₃Br₂) (see Table S6 (ESI⁺)). Such bond length and angle reduction in 0D CHPs signify the fact that our attempt to incorporate Br atoms onto the CHP host lattice affects the proportion ratio between the well-known three STE configurations.^{92,93} Since the first decay component of lifetimes (τ_1) is associated with the direct recombination of excitons,^{74,93,94} we argue that the $[Cu_2X_5]^{3-}$ species in the mixed halide system (I:Br 4:1 and 3:2) powders have a slightly distorted structure compared to their conventional 0D Cs₃Cu₂I₅. This eventually decreased the perovskite volume, mitigating the depth of traps that are largely found in bromine-rich CHPs.⁹⁴ In addition, we postulate that the Jahn-Teller distortion in the d orbital of Cu centres is strongly enhanced when the unequal occupation of the other degenerate t2g 3d orbitals is indirectly affected by their interaction due to Br incorporation.⁴⁹ This, in turn, manifests in the large SS and multiple STE emissions as outlined by previous works.^{29,34,90,94} We believe that such STE modulation not only improves τ_1 but simultaneously reduced the slowest τ_3 proportion significantly (see Table 2). This rationalizes the QY results shown in Table 3 of the reported CHPs by a mechanochemical approach. The indirect interplay between bond lengths and angles due to Br doping is pivotal in shaping the exciton localisation hence STE formation, where such luminescent properties can be used to optimise the desirable scintillation properties with fast decay time with higher τ_1 contribution.

4 Conclusions

In summary, we have investigated the optoelectronics and scintillation properties of 1D ($CsCu_2I_3$) and 0D ($Cs_3Cu_2I_5$, $Cs_3Cu_2I_4$ Br, and $Cs_3Cu_2I_3Br_2$) CHP powders synthesised by

mechanochemistry. 1D CsCu₂I₃ exhibits an impressive SS of 1.65 \pm 0.04 eV accompanied by a short attenuation length (33 to 42 keV), a fast decay component of 9.30 \pm 0.01 ns, and competitive experimental LY (state value) compared to different CHP morphologies such as thin films or single crystals at RT. However, 0D Cs₃Cu₂I₅ exhibits deep traps (~ 500 meV) that gradually converted to shallow traps upon Br doping. In addition, temperature-dependent RL measurements across the entire samples reveal that RL emission diminishes due to TQ. Introducing Br doping in 0D CHP, the observed reduction of QYs in 0D CHP is proposed due to the contribution of surface trap states induced by the Br content within these materials, highlighting the importance of geometric consideration. By carefully adjusting the I:Br ratio, the lattice distortions can impart a minute change in the Jahn-Teller distortion across Cu tetrahedral networks, leading to a localised exciton and hence STE tunability. Thus, dimensionality control and halide compositional engineering shed some light on the future of scintillator-based CHPs.

Author contributions

Conceptualisation: A., L. J. D., and M. D. B.; data curation: P. Y. D. M., S. H., L. Z., D. K., M. E. W., K. J. D., M. M., W. D., and M. D. B.; formal analysis: T. H., A., S. H., A. A. A., M. H. M., L. J. D., and M. D. B.; investigation: T. H., A., S. H., A. A. A., M. H. M., L. J. D., and M. D. B.; methodology: T. H. and L. J. D.; project administration: A., L. J. D., and M. D. B.; resources: A., P. Y. D. M., S. H., M. H. M., L. Z., M. E. W., K. J. D., M. M., W. D., L. J. D., and M. D. B.; supervision: A., L. J. D., and M. D. B.; visualisation: T. H., M. H. M., and M. D. B.; writing – original draft: T. H., A., and L. J. D. and M. D. B.; writing – review and editing: T. H., A., L. J. D., and M. D. B. All authors have read and agreed to the published version of the manuscript.

Conflicts of interest

There are no conflicts to declare.

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References

- 1 M. D. Birowosuto, D. Cortecchia, W. Drozdowski, K. Brylew, W. Lachmanski, A. Bruno and C. Soci, *Sci. Rep.*, 2016, **6**, 37254.
- 2 H. Yu, T. Chen, Z. Han, J. Fan and Q. Pei, *ACS Appl. Nano Mater.*, 2022, 5, 14572–14581.
- 3 A. Wibowo, M. A. K. Sheikh, L. J. Diguna, M. B. Ananda, M. A. Marsudi, A. Arramel, S. Zeng, L. J. Wong and M. D. Birowosuto, *Commun. Mater.*, 2023, 4, 21.
- 4 F. Maddalena, A. Xie, X. Y. Chin, R. Begum, M. E. Witkowski, M. Makowski, B. Mahler, W. Drozdowski, S. V. Springham, R. S. Rawat, N. Mathews, C. Dujardin, M. D. Birowosuto and C. Dang, *J. Phys. Chem. C*, 2021, 125, 14082–14088.
- 5 Q. Xu, J. Wang, W. Shao, X. Ouyang, X. Wang, X. Zhang, Y. Guo and X. Ouyang, *Nanoscale*, 2020, 12, 9727–9732.
- 6 J. Li, H.-L. Cao, W.-B. Jiao, Q. Wang, M. Wei, I. Cantone, J. Lü and A. Abate, *Nat. Commun.*, 2020, 11, 310.
- 7 A. H. Slavney, R. W. Smaha, I. C. Smith, A. Jaffe, D. Umeyama and H. I. Karunadasa, *Inorg. Chem.*, 2017, 56, 46–55.
- 8 M. C. Brennan, J. Zinna and M. Kuno, ACS Energy Lett., 2017, 2, 1487–1488.
- 9 R. Lin, Q. Guo, Q. Zhu, Y. Zhu, W. Zheng and F. Huang, *Adv. Mater.*, 2019, **31**, 1905079.
- 10 L. J. Diguna, L. Jonathan, M. H. Mahyuddin, Arramel, F. Maddalena, I. Mulyani, D. Onggo, A. Bachiri, M. E. Witkowski, M. Makowski, D. Kowal, W. Drozdowski and M. D. Birowosuto, *Mater. Adv*, 2022, 3, 5087–5095.
- 11 Z.-X. Zhang, C. Li, Y. Lu, X.-W. Tong, F.-X. Liang, X.-Y. Zhao, D. Wu, C. Xie and L.-B. Luo, *J. Phys. Chem. Lett.*, 2019, **10**, 5343–5350.
- 12 R. Roccanova, A. Yangui, G. Seo, T. D. Creason, Y. Wu,
 D. Y. Kim, M.-H. Du and B. Saparov, *ACS Mater. Lett.*, 2019,
 1, 459–465.
- L. Lian, M. Zheng, W. Zhang, L. Yin, X. Du, P. Zhang, X. Zhang, J. Gao, D. Zhang, L. Gao, G. Niu, H. Song, R. Chen, X. Lan, J. Tang and J. Zhang, *Adv. Sci.*, 2020, 7, 2000195.
- 14 X. Bin, J. Liu, R. Zeng, H. Liu, J. Zhao and T. Lin, *J. Mater. Chem. C*, 2024, **12**, 922–929.
- 15 J. J. Van Blaaderen, L. A. Van Den Brekel, K. W. Krämer and P. Dorenbos, *Chem. Mater.*, 2023, **35**, 9623–9631.
- 16 P. Yang, G. Liu, B. Liu, X. Liu, Y. Lou, J. Chen and Y. Zhao, *Chem. Commun.*, 2018, 54, 11638–11641.
- S. Cheng, A. Beitlerova, R. Kucerkova, E. Mihokova, M. Nikl,
 Z. Zhou, G. Ren and Y. Wu, *ACS Appl. Mater. Interfaces*, 2021,
 13, 12198–12202.
- 18 S. Cheng, A. Beitlerova, R. Kucerkova, M. Nikl, G. Ren and Y. Wu, *Phys. Status Solidi RRL*, 2020, **14**, 2000374.
- 19 D. Yuan, ACS Appl. Mater. Interfaces, 2020, 12, 38333-38340.

- 20 Q. Yao, J. Li, X. Li, X. Zheng, Z. Wang and X. Tao, Adv. Opt. Mater., 2022, 10, 2201161.
- 21 Z. Ma, X. Ji, S. Lin, X. Chen, D. Wu, X. Li, Y. Zhang, C. Shan, Z. Shi and X. Fang, *Adv. Mater.*, 2023, 2300731.
- 22 S. Li, Z. Shi, F. Zhang, L. Wang, Z. Ma, D. Yang, Z. Yao, D. Wu, T.-T. Xu, Y. Tian, Y. Zhang, C. Shan and X. J. Li, *Chem. Mater.*, 2019, **31**, 3917–3928.
- 23 X. Huang, Q. Sun and B. Devakumar, *Mater. Today Chem.*, 2020, 17, 100288.
- 24 Y. Liu, M. S. Molokeev and Z. Xia, *Energy Mater. Adv.*, 2021, 2021, 2585274.
- 25 J.-M. Yang, Y.-K. Jung, J.-H. Lee, Y. C. Kim, S.-Y. Kim, S. Seo, D.-A. Park, J.-H. Kim, S.-Y. Jeong, I.-T. Han, J.-H. Park, A. Walsh and N.-G. Park, *Nanoscale Horiz.*, 2021, 6, 987–997.
- 26 L. Manna, O. M. Bakr, S. Brovelli and H. Li, *Energy Mater. Adv.*, 2022, 2022, 9865891.
- 27 Z. Luo, Q. Li, L. Zhang, X. Wu, L. Tan, C. Zou, Y. Liu and Z. Quan, *Small*, 2020, **16**, 1905226.
- 28 Y. Li, P. Vashishtha, Z. Zhou, Z. Li, S. B. Shivarudraiah, C. Ma, J. Liu, K. S. Wong, H. Su and J. E. Halpert, *Chem. Mater.*, 2020, **32**, 5515–5524.
- 29 R. Roccanova, A. Yangui, H. Nhalil, H. Shi, M.-H. Du and B. Saparov, *ACS Appl. Electron. Mater.*, 2019, **1**, 269–274.
- 30 V. Scailteur and R. R. Lauwerys, Toxicology, 1987, 43, 231-238.
- 31 E. G. Worthley and C. D. Schott, *Toxicol. Appl. Pharmacol.*, 1969, **15**, 275–281.
- 32 S. Fang, Y. Wang, H. Li, F. Fang, K. Jiang, Z. Liu, H. Li and Y. Shi, *J. Mater. Chem. C*, 2020, **8**, 4895–4901.
- 33 G. K. Grandhi, N. S. M. Viswanath, H. B. Cho, J. H. Han, S. M. Kim, S. Choi and W. B. Im, *J. Phys. Chem. Lett.*, 2020, 11, 7723–7729.
- 34 P. Sebastia-Luna, J. Navarro-Alapont, M. Sessolo, F. Palazon and H. J. Bolink, *Chem. Mater.*, 2019, **31**, 10205–10210.
- 35 N. Doebelin and R. Kleeberg, J. Appl. Cryst., 2015, 48, 1573-1580.
- 36 K. Momma and F. Izumi, J. Appl. Cryst., 2011, 44, 1272-1276.
- N. Fairley, V. Fernandez, M. Richard-Plouet, C. Guillot-Deudon, J. Walton, E. Smith, D. Flahaut, M. Greiner, M. Biesinger, S. Tougaard, D. Morgan and J. Baltrusaitis, *Appl. Surf. Sci.*, 2021, 5, 100112.
- 38 P. Hohenberg and W. Kohn, Phys. Rev., 1964, 136, B864-B871.
- 39 W. Kohn and L. J. Sham, Phys. Rev., 1965, 140, A1133-A1138.
- 40 G. Kresse and J. Furthmüller, *Comput. Mater. Sci.*, 1996, 6, 15–50.
- 41 G. Kresse and J. Furthmüller, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1996, **54**, 11169–11186.
- 42 P. E. Blöchl, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1994, 50, 17953–17979.
- 43 G. Kresse and D. Joubert, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1999, **59**, 1758–1775.
- 44 J. P. Perdew, K. Burke and M. Ernzerhof, *Phys. Rev. Lett.*, 1996, 77, 3865–3868.
- 45 S. L. Dudarev, G. A. Botton, S. Y. Savrasov, C. J. Humphreys and A. P. Sutton, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1998, 57, 1505–1509.
- 46 H. J. Monkhorst and J. D. Pack, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1976, 13, 5188–5192.

- 47 S. Grimme, J. Antony, S. Ehrlich and H. Krieg, *J. Chem. Phys.*, 2010, **132**, 154104.
- 48 L. Xie, B. Chen, F. Zhang, Z. Zhao, X. Wang, L. Shi, Y. Liu,
 L. Huang, R. Liu, B. Zou and Y. Wang, *Photon. Res.*, 2020,
 8, 768.
- 49 T. Jun, K. Sim, S. Iimura, M. Sasase, H. Kamioka, J. Kim and H. Hosono, *Adv. Mater.*, 2018, **30**, 1804547.
- 50 F. Zhang, Z. Zhao, B. Chen, H. Zheng, L. Huang, Y. Liu,
 Y. Wang and A. L. Rogach, *Adv. Opt. Mater.*, 2020,
 8, 1901723.
- 51 F. Maddalena, M. E. Witkowski, M. Makowski, A. Bachiri, Arramel, T. Yang, M. H. Mahyuddin, M. Baravaglio, M. Boutchich, W. Drozdowski, C. Dujardin, M. D. Birowosuto and C. Dang, *J. Mater. Chem. C*, 2022, **10**, 11266–11275.
- 52 Arramel, A. Xie, X. Yin, C. S. Tang, M. H. Mahyuddin, C. Hettiarachchi, M. F. Sahdan, K. Yoshizawa, C. Dang, M. D. Birowosuto, A. T. S. Wee and A. Rusydi, ACS Appl. Energy Mater., 2020, 3, 7500–7511.
- 53 S. Hartati, P. Y. D. Maulida, T. Zakly, I. Mulyani, D. Onggo,
 M. H. Mahyuddin, A. Noviyanto, A. Arramel and N. T. Rochman, *NHC*, 2023, 40, 1–6.
- 54 L. J. Diguna, S. Kaffah, M. H. Mahyuddin, Arramel, F. Maddalena, S. A. Bakar, M. Aminah, D. Onggo, M. E. Witkowski, M. Makowski, W. Drozdowski and M. D. Birowosuto, *RSC Adv.*, 2021, **11**, 20635–20640.
- 55 P. Y. D. Maulida, D. Wang, F. Maddalena, C. S. Tang, X. Yin,
 C. Diao, I. Mulyani, D. Onggo, A. Noviyanto,
 M. D. Birowosuto, Arramel, A. T. S. Wee and A. Rusydi, *J. Phys. Chem. C*, 2022, 126, 15801–15808.
- 56 H. Lei, D. Hardy and F. Gao, *Adv. Funct. Mater.*, 2021, **31**, 2105898.
- 57 G. S. Long, M. Wei and R. D. Willett, *Inorg. Chem.*, 1997, 36, 3102–3107.
- 58 A. M. Elseman, A. E. Shalan, S. Sajid, M. M. Rashad,
 A. M. Hassan and M. Li, ACS Appl. Mater. Interfaces, 2018, 10, 11699–11707.
- 59 Y. Zhou, X. Wang, T. He, H. Yang, C. Yang, B. Shao, L. Gutiérrez-Arzaluz, O. M. Bakr, Y. Zhang and O. F. Mohammed, ACS Energy Lett., 2022, 7, 844–846.
- 60 J. Qu, S. Xu, H. Shao, P. Xia, C. Lu, C. Wang and D. Ban, J. Mater. Chem. C, 2023, 11, 6260–6275.
- 61 L. Lian, M. Zheng, P. Zhang, Z. Zheng, K. Du, W. Lei, J. Gao, G. Niu, D. Zhang, T. Zhai, S. Jin, J. Tang, X. Zhang and J. Zhang, *Chem. Mater.*, 2020, **32**, 3462–3468.
- 62 R. J. Elliott, Phys. Rev., 1957, 108, 1384-1389.
- 63 B. Ullrich, A. K. Singh, P. Barik, H. Xi and M. Bhowmick, *Opt. Lett.*, 2015, **40**, 2580.
- 64 Q. Li, Z. Chen, B. Yang, L. Tan, B. Xu, J. Han, Y. Zhao, J. Tang and Z. Quan, J. Am. Chem. Soc., 2020, 142, 1786–1791.
- P. Vashishtha, G. V. Nutan, B. E. Griffith, Y. Fang,
 D. Giovanni, M. Jagadeeswararao, T. C. Sum, N. Mathews,
 S. G. Mhaisalkar, J. V. Hanna and T. White, *Chem. Mater.*,
 2019, 31, 9003–9011.
- 66 X. Liu, Y. Yu, F. Yuan, C. Zhao, H. Dong, B. Jiao and Z. Wu, ACS Appl. Mater. Interfaces, 2020, 12, 52967–52975.

- 67 Y. Tratsiak, L. Stand, R. Lalk, M. Zhuravleva and C. L. Melcher, J. Lumin., 2023, 263, 119952.
- 68 B. Liu, Y. Sun, L. Chen, B. Liao, J. Ruan, L. Zhou, Y. Li and X. Ouyang, *Inorg. Chem.*, 2022, **61**, 16141–16147.
- 69 F. Maddalena, A. Xie, Arramel, M. E. Witkowski, M. Makowski, B. Mahler, W. Drozdowski, T. Mariyappan, S. V. Springham, P. Coquet, C. Dujardin, M. D. Birowosuto and C. Dang, *J. Mater. Chem. C*, 2021, **9**, 2504–2512.
- 70 J. T. Randall and M. H. F. W. Wilkins, Proc. R. Soc. London, Ser. A, 1945, 184, 365–389.
- 71 P. Schulz, ACS Energy Lett., 2018, 3, 1287-1293.
- 72 C. Giansante and I. Infante, J. Phys. Chem. Lett., 2017, 8, 5209-5215.
- Y. Hu, E. M. Hutter, P. Rieder, I. Grill, J. Hanisch, M. F. Aygüler,
 A. G. Hufnagel, M. Handloser, T. Bein, A. Hartschuh,
 K. Tvingstedt, V. Dyakonov, A. Baumann, T. J. Savenije, M. L.
 Petrus and P. Docampo, *Adv. Energy Mater.*, 2018, 8, 1703057.
- 74 F. Maddalena, L. Tjahjana, A. Xie, Arramel, S. Zeng, H. Wang, P. Coquet, W. Drozdowski, C. Dujardin, C. Dang and M. Birowosuto, *Crystals*, 2019, 9, 88.
- 75 E. V. D. van Loef, P. Dorenbos, C. W. E. van Eijk, K. W. Krämer and H. U. Güdel, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2003, 68, 045108.
- 76 Y. Zhou, Z. Deng, B. Wang, P. Li, L. Li, W. Han, J. Huang, W. Jia, X. Ouyang, Q. Xu and K. K. Ostrikov, *Chem. Eng. J.*, 2023, 471, 144431.
- 77 V. Naresh, S. Singh, H. Soh, J. Lee and N. Lee, *Mater. Today* Nano, 2023, 100364.
- 78 M. S. J. Marshall, J. Wang, S. Miller, B. Singh and V. Nagarkar, 2020 IEEE Nuclear Science Symposium and Medical Imaging Conference (NSS/MIC), Boston, MA, USA, 2020, pp. 1–2.
- 79 J. Liu, W. Shao, Q. Xu, Y. Liu and X. Ouyang, *IEEE Photon. Technol. Lett.*, 2020, 32, 635–638.
- 80 Q. Xu, J. Wang, Q. Zhang, X. Ouyang, M. Ye, W. Xie, X. Yan, D. Li,
 X. Ouyang, X. Tang and X. Zhang, *Photon. Res.*, 2021, 9, 351.
- 81 Z. Ma, Z. Shi, C. Qin, M. Cui, D. Yang, X. Wang, L. Wang, X. Ji, X. Chen, J. Sun, D. Wu, Y. Zhang, X. J. Li, L. Zhang and C. Shan, *ACS Nano*, 2020, **14**, 4475–4486.
- 82 N. Li, Z. Xu, Y. Xiao, Y. Liu, Z. Yang and S. F. Liu, *Adv. Opt. Mater.*, 2022, **10**, 2102232.
- 83 T. Jiang, J. Wang, L. Xie, C. Bai, M. Wang, Y. Wu, F. Zhang,
 Y. Zhao, B. Chen and Y. Wang, *ACS Appl. Nano Mater.*, 2022,
 5, 508–516.
- 84 M. D. Birowosuto and P. Dorenbos, *Phys. Status Solidi A*, 2009, 206, 9–20.
- 85 M.-H. Du, ACS Energy Lett., 2020, 5, 464-469.
- 86 R. Lin, Q. Zhu, Q. Guo, Y. Zhu, W. Zheng and F. Huang, J. Phys. Chem. C, 2020, 124, 20469–20476.
- 87 Y.-K. Jung, S. Kim, Y. C. Kim and A. Walsh, J. Phys. Chem. Lett., 2021, 12, 8447–8452.
- 88 Y. Hu, X. Yan, L. Zhou, P. Chen, Q. Pang and Y. Chen, J. Phys. Chem. Lett., 2022, 13, 10786–10792.
- 89 M. A. Halcrow, Chem. Soc. Rev., 2013, 42, 1784-1795.
- 90 H. Chen, J. M. Pina, F. Yuan, A. Johnston, D. Ma, B. Chen, Z. Li, A. Dumont, X. Li, Y. Liu, S. Hoogland, Z. Zajacz, Z. Lu and E. H. Sargent, *J. Phys. Chem. Lett.*, 2020, **11**, 4326–4330.

Paper

- 91 Z. Ma, Z. Shi, D. Yang, Y. Li, F. Zhang, L. Wang, X. Chen, D. Wu, Y. Tian, Y. Zhang, L. Zhang, X. Li and C. Shan, *Adv. Mater.*, 2021, 33, 2001367.
- 92 R. Kentsch, M. Morgenroth, M. Scholz, K. Xu, J. Schmedt Auf Der Günne, T. Lenzer and K. Oum, *J. Phys. Chem. Lett.*, 2020, **11**, 4286–4291.
- 93 C.-Y. Chen, Y.-I. Lin, P.-T. Lai, H.-C. Lin, G.-H. Tan, H.-W. Lin and R. D. Schaller, *Adv. Opt. Mater.*, 2022, 10, 2200005.
- 94 G. F. Samu, T. S. Zsigmond, C. Hajdu, M. Hunyadi, L. Csige, A. Csík, J. Kopniczky, B. Hopp and C. Janáky, *Adv. Opt. Mater.*, 2023, 2300825.